Diode Semiconductor Device - Page 1 of 1



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Inclosure	Material:
Metal	
Overall Le	ngth:
1.253 inche	€S
End Applie	cation:
Generator	76301
Mounting	Facility Quantity:
1	
Mounting	Method:
Threaded s	stud
Features F	Provided:
Hermetical	ly sealed case
Overall Wi	dth Across Flats:
0.437 inche	≥S
Thread Siz	2e:
0.190 inche	≥S
Criticality	Code Justification:
Feat	
Semicond	uctor Material:
Silicon	
Voltage Ra	ating In Volts Per Characteristic:
33.0 regu	lator voltage
Current Ra	ating Per Characteristic:
75.00 millia	amperes source cutoff current horsepower metric
Power Rat	ing Per Characteristic:
10.0 watts	small-signal input power, common-collector preset
Maximum	Operating Tempurature Per Measurement Point:
175.0 degr	ees celsius junction
Special Fe	atures:
Weapon sy	vstem essential
Thread Se	ries Designator:
Unf	
Terminal 1	Type And Quantity:
1 threaded	stud and 1 tab, solder lug
Shelf Life:	
N/a	
Unit Of Me	asure:
Demilitariz	zation:
No	
Fiig:	
A110a0	